

# INA148 ±200V Common-mode Voltage Difference Amplifier

#### 1 Features

- High common-mode voltage:
  - +75V at  $V_S = +5V$
  - ±200V at  $V_S = \pm 15V$
- Fixed differential gain = 1V/V
- Low quiescent current: 260µA
- Wide supply range:
  - Single supply: 2.7V to 36V
  - Dual supplies: ±1.35V to ±18V
- Low gain error: 0.075% maximum
- Low non-linearity: 0.002% maximum
- High CMRR: 86dB
- SOIC-8 Package

## 2 Applications

- Battery cell formation and test equipment
- Battery management systems
- Analog input module
- Mixed module (AI, AO, DI, DO)
- DC fast charging power module
- String inverter

### 3 Description

The INA148 is a precision, low-power, unity-gain difference amplifier with a high common-mode input voltage range. The device consists of a monolithic precision bipolar op amp with a thin-film resistor network.

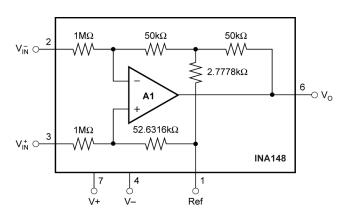
The on-chip resistors are laser trimmed for an accurate 1V/V differential gain and high commonmode rejection. Excellent temperature tracking of the resistor network maintains high gain accuracy and common-mode rejection over temperature. The INA148 operates on single or dual supplies.

The INA148 is available in SOIC-8 surface-mount package and is specified for the -40°C to +85°C industrial temperature range.

### **Package Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>		
INA148	D (SOIC, 8)	4.9mm × 6mm		

- For more information, see Section 9. (1)
- The package size (length × width) is a nominal value and includes pins, where applicable.



**Simplified Schematic** 



## **Table of Contents**

1 Features	1 6.1 Application Information
2 Applications	··
3 Description	
4 Pin Configuration and Functions	
5 Specifications	
5.1 Absolute Maximum Ratings	
5.2 Recommended Operating Conditions	
5.3 Thermal Information	
5.4 Electrical Characteristics	<u>.</u>
5.5 Typical Characteristics	
6 Application and Implementation1	

# 4 Pin Configuration and Functions

TOP VIEW SO-8

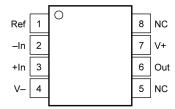


Figure 4-1. D Package, 8-Pin SOIC (Top View)

### **Table 4-1. Pin Functions**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION	
NAME	NO.	1115	DESCRIPTION	
-IN	2	I	Negative (inverting) input	
+IN	3	ı	Positive (non-inverting) input	
NC	5, 8	NC	No connect.	
Out	6	0	Output	
Ref	1	I	Reference input	
V-	4	-	Negative power supply	
V+	7	-	Positive power supply	

(1) I=Input; O=Output; NC = No Connect.

## 5 Specifications

#### **Note**

TI has qualified multiple fabrication flows for this device. Differences in performance are labeled by chip site origin (CSO). For system robustness, designing for all flows is highly recommended. For more information, please see Section 7.1.

### **5.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>S</sub>	Supply voltage	Dual supply, $V_S = (V+) - (V-)$		±18	V
	Supply voltage	Single supply, $V_S = (V+) - 0V$		36	
	Signal input ping	Continuous		±200	V
	Signal input pins	Peak (0.1s)		±500	V
	Output short-circuit <sup>(2)</sup>		Continuous		
T <sub>A</sub>	Operating temperature		-55	125	°C
T <sub>stg</sub>	Storage temperature	-55	125	°C	
	Junction temperature		150	°C	
	Lead temperature (sold	ering, 10s)		300	°C

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

### **5.2 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

			MIN	TYP	MAX	UNIT
V 6	Supply voltage	Single-supply	2.7	30	36	W
V <sub>S</sub>	Supply voltage	Dual-supply	±1.35	±15	±18	V
T <sub>A</sub>	Specified temperature		-40		85	°C

#### 5.3 Thermal Information

		INA148	
	THERMAL METRIC <sup>(1)</sup>	D (SOIC)	UNIT
		8 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance	150	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

<sup>(2)</sup> Short-circuit to V<sub>S</sub> / 2.



## **5.4 Electrical Characteristics**

at  $T_A$  = 25°C,  $V_S$  = ±5V to ±15V,  $R_L$  = 10k $\Omega$ ,  $V_{REF}$  =  $V_S$  / 2,  $V_{CM}$  =  $V_S$  / 2, and all chip site origins (CSO), (unless otherwise noted)

	PARAMETER		TEST CONDITION	IS	MIN	TYP	MAX	UNIT
INPUT		1						
	Off 1 11 (DTI) (1) (4)	V <sub>S</sub> = ±15V	V <sub>S</sub> = ±15V			±1	±5	.,
Vos	Offset voltage (RTI) (1) (4)	V <sub>S</sub> = ±5V				±1	±5	mV
	Offset voltage drift (RTI)(1)	$T_A = -40^{\circ}C \text{ to } 85^{\circ}$	<sub>A</sub> = -40°C to 85°C			±10		μV/°C
PSRR	Power-supply rejection ratio	\/4.25\/±	40)/	CSO: SHE		±50	±400	\/\/
PSKK	(RTI) <sup>(1)</sup>	$V_S = \pm 1.35V \text{ to } \pm 1.35$	187	CSO: TID		±3.5	±80	μV/V
			V <sub>S</sub> = ±15V	•	-200		200	
V	Common made valtage (2)	\/ = 0\/	V <sub>S</sub> = ±5V		-100		100	V
V <sub>CM</sub>	Common-mode voltage (2)	$V_O = 0V$	$V_S = +5V^{(3)}, V_{REF}$	= V <sub>S</sub> / 2	-47.5		32.5	V
			$V_S = +5V^{(3)}, V_{REF}$	= = 0.25V	-4		75	
		V <sub>S</sub> = ±15V, V <sub>CM</sub> =	-200V to 200V, R	<sub>S</sub> = 0Ω	70	86		
CMRR	Common-mode voltage rejection	V <sub>S</sub> = ±5V, V <sub>CM</sub> = -	–100V to 80V, R <sub>S</sub> =	: 0Ω	70	86		dB
	1.0,000.011	$V_S = +5V^{(3)}$ , $V_{CM} = -47.5V$ to 32.5V, $R_S = 0\Omega$			70	86		
	Differential input impedance					2		
	Common-mode input impedance					1		ΜΩ
_	\( \( \tau \) = \( \tau \) = \( \tau \) \( \	f <sub>B</sub> = 0.1Hz to 10Hz				17		μV <sub>PP</sub>
e <sub>N</sub>	Voltage noise (RTI) <sup>(1) (5)</sup>	f = 1kHz				880		nV/√ <del>Hz</del>
GAIN								
	Initial					1		V/V
GE	Gain error	V <sub>O</sub> = (V–) + 0.5V	to (V+) – 1.5V			±0.01	±0.075	%
	Gain error drift	$T_A = -40^{\circ}\text{C to } +88$	5°C			±3	±10	ppm/°C
		\( - \( \) \ \ 0 \ E\\( \)	to (\(\(\)\\) 1 E\(\)	V <sub>S</sub> = ±15V		±0.001	±0.002	
	Gain nonlinearity	V <sub>O</sub> = (V=) + 0.5V	$V_O = (V-) + 0.5V \text{ to } (V+) - 1.5V$ $V_S = \pm 0.5V$			±0.001		% of FSR
$V_S = +5V^{(3)}, V_O = 0.5V \text{ to } 3.5V$					±0.001			
OUTPUT					•			
	Output voltage	$R_L = 100k\Omega$			(V-) + 0.25		(V+) – 1	V
	Output voltage	$R_L = 10k\Omega$			(V-) + 0.5		(V+) – 1.5	V
C <sub>L</sub>	Load capacitance	Stable operation				10		nF
			CSO: SHE			±13		
$I_{SC}$	Short-circuit current	Continuous to V <sub>S</sub> / 2	CSU: SHE	$V_S = +5V^{(3)}$		±8		mA
		-5.2	CSO: TID			±20		

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## **5.4 Electrical Characteristics (continued)**

at  $T_A$  = 25°C,  $V_S$  = ±5V to ±15V,  $R_L$  = 10k $\Omega$ ,  $V_{REF}$  =  $V_S$  / 2,  $V_{CM}$  =  $V_S$  / 2, and all chip site origins (CSO), (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	3	MIN	TYP	MAX	UNIT
FREQU	ENCY RESPONSE	'						
BW	Bandwidth, –3dB	CSO: SHE	CSO: SHE			100		kHz
DVV	Bandwidth, –3dB	CSO: TID				155		KIIZ
SR	Slew rate					1		V/µs
			V <sub>S</sub> = ±15V, V <sub>O</sub> =	CSO: SHE		21		
			10V step	CSO: TID		15		
		To 0.1%	V <sub>S</sub> = ±5V, V <sub>O</sub> =	CSO: SHE		21		
	Settling time	10 0.170	6V step	CSO: TID		15		
			$V_S = +5V^{(3)}, V_O = 3V \text{ step}$			21		
t <sub>S</sub>			V <sub>S</sub> = ±15V, V <sub>O</sub> = 10V step	CSO: SHE		25		μs
				CSO: TID		23		
		To 0.01%	$V_S = \pm 5V$ , $V_O = 6V$ step	CSO: SHE		25		
		10 0.0 1 70		CSO: TID		23		
			$V_S = +5V^{(3)}, V_O = 3V \text{ step}$			25		
			CSO: SHE			4		
	Overload recovery	50% input overload	CSO: TID			1.2		μs
			$V_S = +5V^{(3)}$			3		
POWER	SUPPLY		•				'	
IQ	Quiescent current	V <sub>IN</sub> = 0V				±260	±300	μΑ

<sup>(1)</sup> RTI stands for Referred to Input

<sup>(2)</sup> Input common-mode voltage varies with output voltage; see Section 5.5.

<sup>(3)</sup>  $V_S = +5V$  single supply means  $V_{S+} = +5V$  and  $V_{S-} = GND$ 

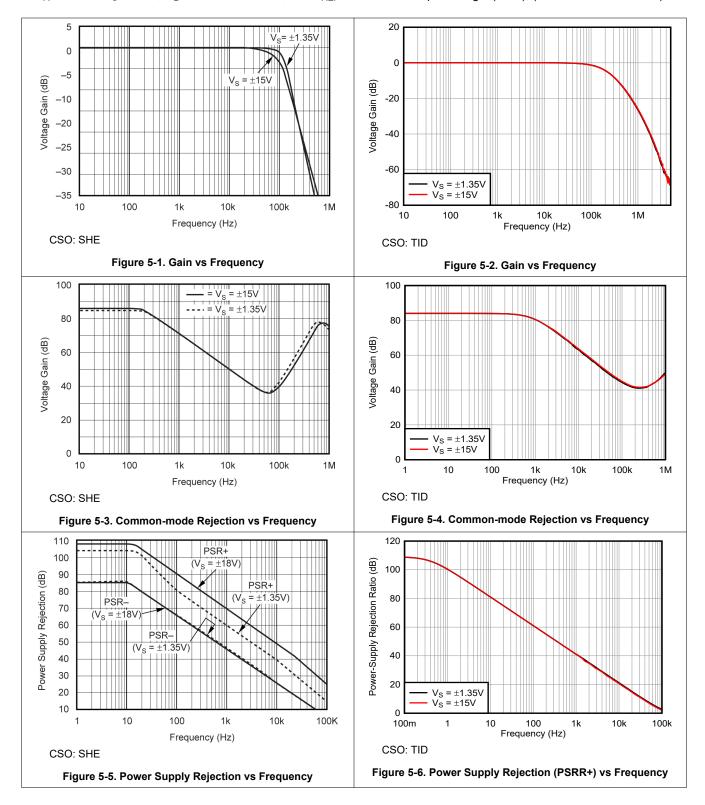
<sup>(4)</sup> Input offset voltage specification includes effects of input bias current and offset current of amplifier

<sup>(5)</sup> Includes effects of input current noise and thermal noise contributor of resistor network

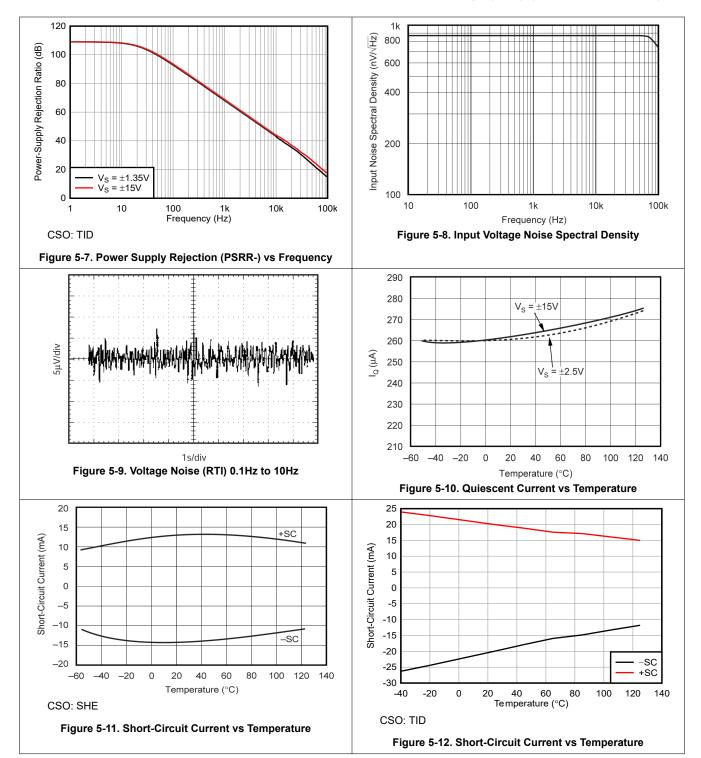


### 5.5 Typical Characteristics

At  $T_A = +25$ °C,  $V_S = \pm 15$ V,  $R_L = 10$ k $\Omega$  to common, and  $V_{REF} = 0$ V, and all chip site origin (CSO), (unless otherwise noted)

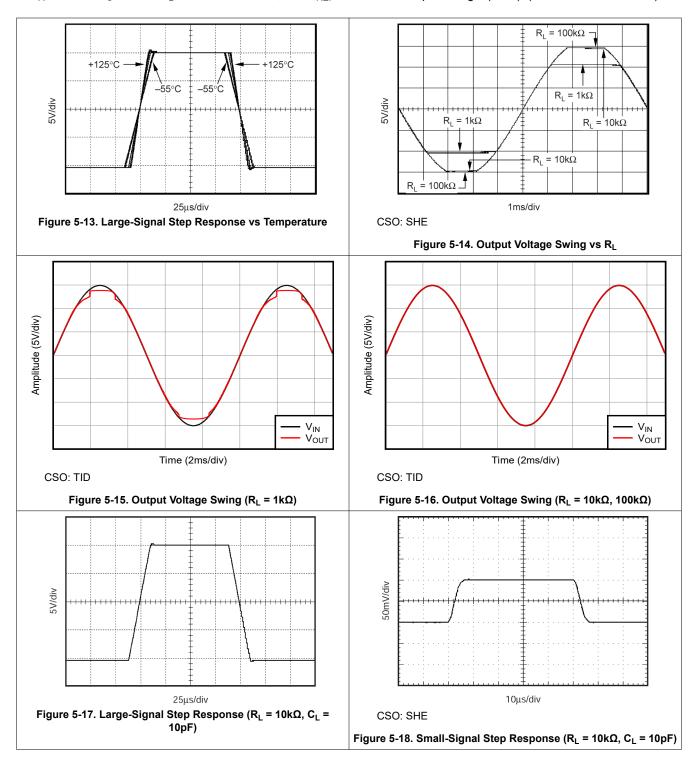


At  $T_A = +25$ °C,  $V_S = \pm 15$ V,  $R_L = 10$ k $\Omega$  to common, and  $V_{REF} = 0$ V, and all chip site origin (CSO), (unless otherwise noted)

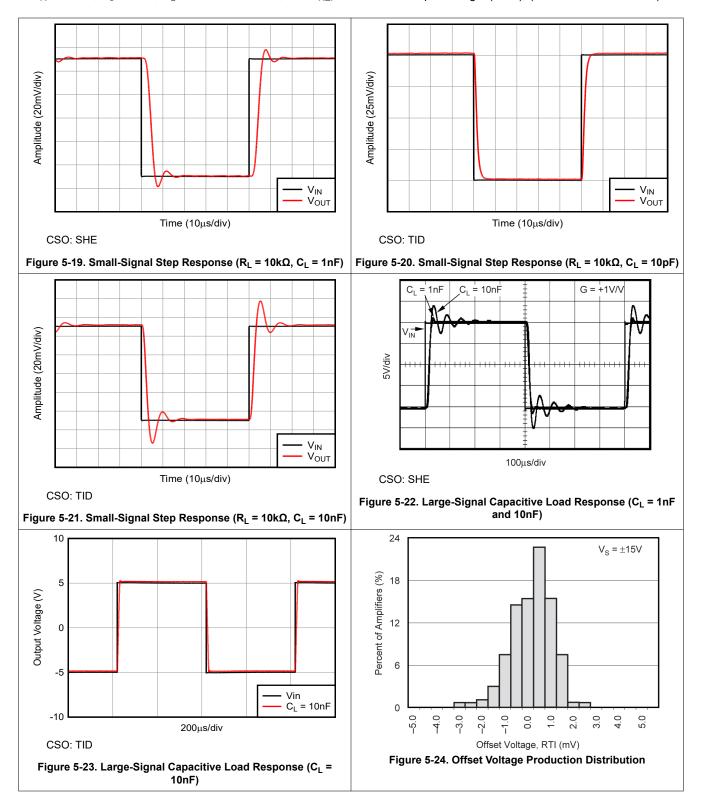




At  $T_A$  = +25°C,  $V_S$  = ±15V,  $R_L$  = 10k $\Omega$  to common, and  $V_{REF}$  = 0V, and all chip site origin (CSO), (unless otherwise noted)

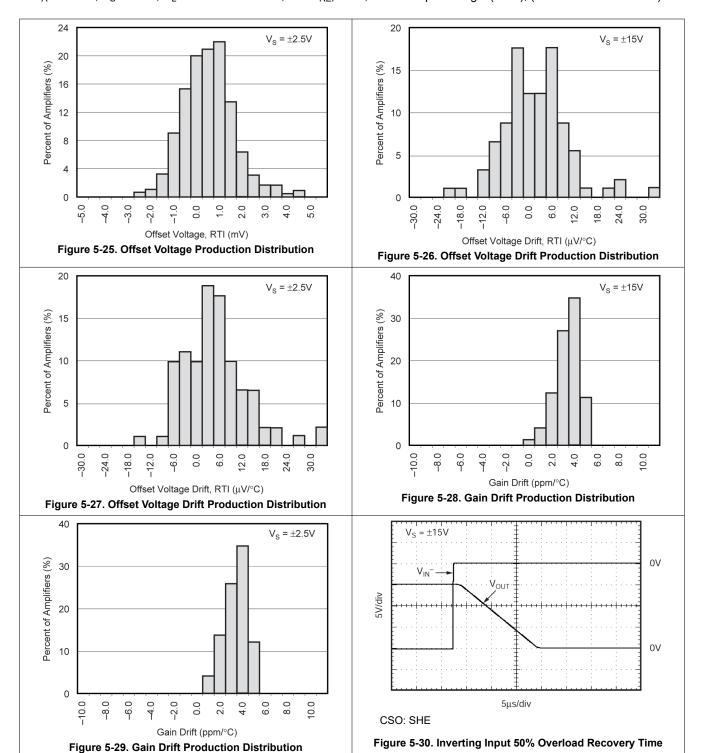


At  $T_A = +25$ °C,  $V_S = \pm 15$ V,  $R_L = 10$ k $\Omega$  to common, and  $V_{REF} = 0$ V, and all chip site origin (CSO), (unless otherwise noted)

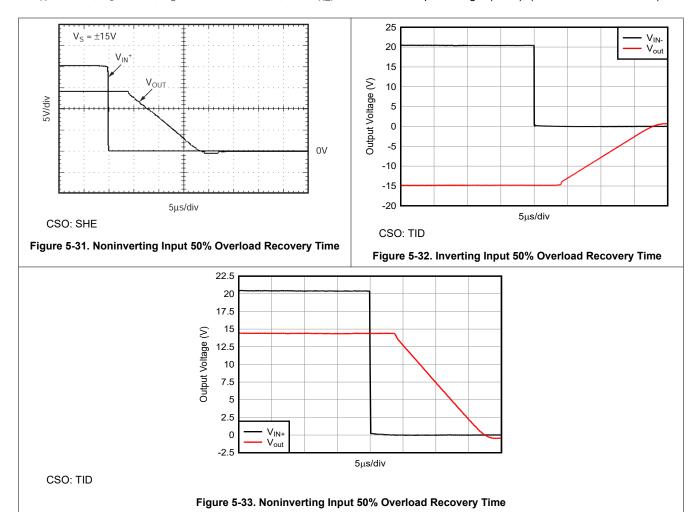




At  $T_A$  = +25°C,  $V_S$  = ±15V,  $R_L$  = 10k $\Omega$  to common, and  $V_{REF}$  = 0V, and all chip site origin (CSO), (unless otherwise noted)



At  $T_A = +25$ °C,  $V_S = \pm 15$ V,  $R_L = 10$ k $\Omega$  to common, and  $V_{REF} = 0$ V, and all chip site origin (CSO), (unless otherwise noted)



## 6 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### **6.1 Application Information**

The INA148 is a unity gain difference amplifier with a high common-mode input voltage range. A basic diagram of the circuit and pin connections is shown in Figure 6-1.

To achieve the high common-mode voltage range, the INA148 features a precision laser-trimmed thin-film resistor network with a 20:1 input voltage divider ratio. High input voltages are thereby reduced in amplitude to bring both positive and negative inputs of the internal operational amplifier within linear operating range. A "Tee" network in the operational amplifier feedback network places the amplifier in a gain of 20V/V, thus restoring the overall gain to unity (1V/V) of the circuit.

External voltages can be summed into the output of the amplifier by using the Ref pin, making the differential amplifier a highly versatile design tool. Voltages on the Ref pin also influence the common-mode voltage range of the INA148.

Use low ESR, power supply bypass capacitors and connect as close to pins 4 and 7 as practicable. Bypass capacitors reduce coupled noise by providing low impedance power sources local to analog circuitry. Ceramic or tantalum types are recommended for use as bypass capacitors.

The input impedance of the INA148 must be considered when routing input signal traces on a PCB board. Avoid placing digital signal traces near the input traces of the difference amplifier to minimize noise pickup.

#### 6.1.1 Operating Voltage

The INA148 is specified for ±15V and ±5V dual supplies and +5V single supplies. The INA148 can be operated with single or dual supplies with excellent performance.

The INA148 is fully characterized for supply voltages from ±1.35V to ±18V and over temperatures of –40°C to +125°C. Parameters that vary with operating voltage, load conditions, or temperature are shown in the Typical Performance section.

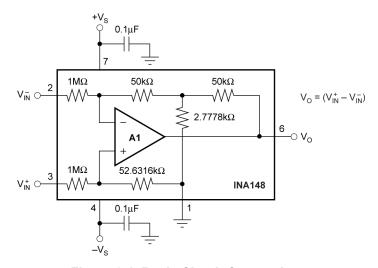


Figure 6-1. Basic Circuit Connections.

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#### 6.1.2 Gain Equation

An internal on-chip resistor network sets the overall differential gain of the INA148 to precisely 1V/V. The output is accordance with the equation:

$$V_{OUT} = \left(V^{\dagger}_{IN} - V^{\dagger}_{IN}\right) + V_{REF} \tag{1}$$

### 6.1.3 Common-Mode Range

The 20:1 input resistor ratio of the INA148 provides an input common-mode range that extends well beyond the power supply rails.

The exact input voltage range depends on the amplifier power supply voltage and the voltage applied to the Ref terminal (pin 1). Typical input voltage ranges at different power supply voltages can be found in the Section 6.2 section.

Do not attempt to extend the INA148 input voltage range further by adding external resistors as this degrades CMRR.

#### 6.1.4 Offset Trim

The INA148 is laser-trimmed for low offset voltage and drift. Most applications require no external offset adjustment.

A voltage applied to the reference pin (Ref, pin 1) is summed directly into the amplifier output signal. Therefore, this technique can be used to null the amplifier input offset voltage. Figure 6-2 shows an optional circuit for trimming the offset voltage.

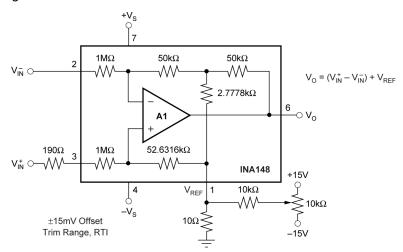


Figure 6-2. Optional Offset Trim Voltage.

To maintain high common-mode rejection (CMRR), verify that the source impedance of any signal applied to the Ref pin is very low ( $\leq 5\Omega$ ).

A source impedance of only  $10\Omega$  at the Ref pin reduces the INA148 CMRR to approximately 74dB. High CMRR can be restored if a resistor is added in series with the amplifier positive input (pin 3). Use a resistor that is 19 times the source impedance that drives the Ref pin. For example, if the Ref pin has a source impedance of  $10\Omega$ , add a resistor of  $190\Omega$  in series with pin 3.

Preferably, buffer the offset trim voltage applied to the Ref pin with an amplifier such as an OPA237 (see Figure 6-3). In this case, the operational amplifier output impedance is low enough that no external resistor is needed to maintain the INA148 excellent CMRR.



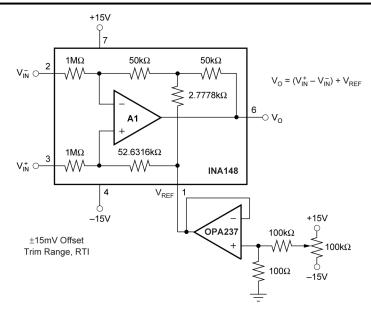


Figure 6-3. Preferred Offset Trim Circuit.

#### 6.1.5 Input Impedance

The input resistor network determines the impedance of each of the INA148 inputs; approximately  $1M\Omega$ . Unlike an instrumentation amplifier, signal source impedance at the two input terminals must be nearly equal to maintain good common-mode rejection.

A mismatch between the two inputs source impedance causes a differential amplifier common-mode rejection to be degraded. With a source impedance imbalance of only  $500\Omega$ , CMRR can fall to approximately 66dB.

Figure 6-4 shows a common application: measuring power supply current through a shunt resistor (R<sub>S</sub>). A shunt resistor creates an unbalanced source resistance condition that can degrade a differential amplifier common-mode rejection.

Unless the shunt resistor is less than approximately  $100\Omega$ , use an additional equal compensating resistor (R<sub>C</sub>) to maintain input balance and high CMRR.

Source impedances (or shunts) greater than  $5k\Omega$  are not recommended, even if well compensated. The internal resistor network is laser-trimmed for accurate voltage divider ratios, but not necessarily to absolute values. Input resistors are shown as  $1M\Omega$ ; however, this value is only nominal.

In practice, the input resistors absolute values can vary by as much as 30 percent. The two input resistors match to about 5 percent. Therefore, adding compensating resistors greater than  $5k\Omega$  can cause a serious mismatch in the resulting resistor network voltage divider ratios, thus degrading CMR.

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## **6.2 Typical Applications**

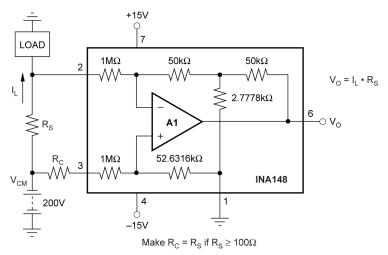
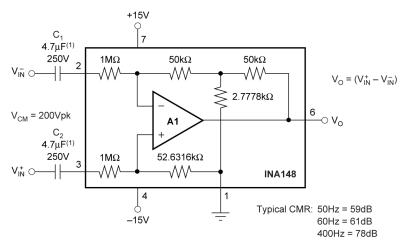


Figure 6-4. Shunt-Resistor Current Measurement Circuit



1. Metallized polypropylene, ±5% tolerance.

Figure 6-5. AC-Coupled Difference Amplifier



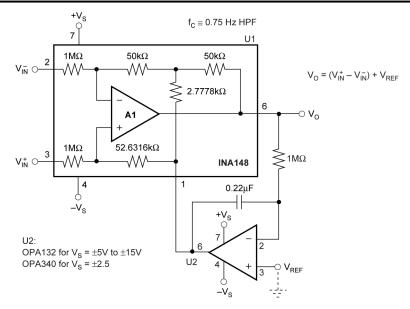


Figure 6-6. Quasi-AC-Coupled Differential Amplifier

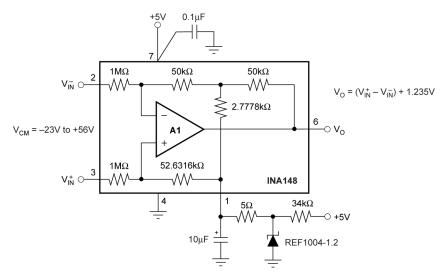


Figure 6-7. Single-Supply Differential Amplifier

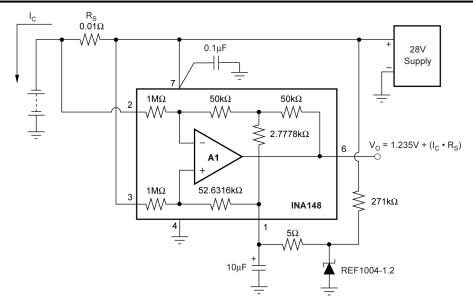


Figure 6-8. Battery Monitor Circuit

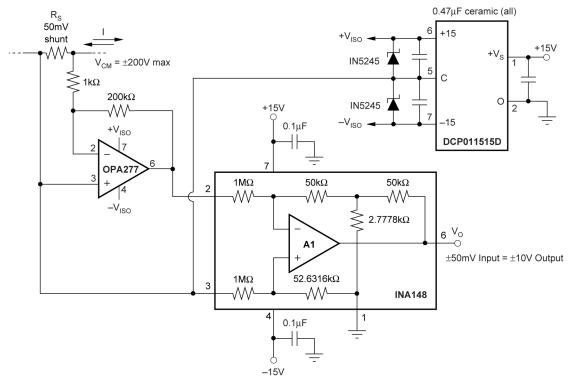


Figure 6-9. 50mV Current Shunt Amplifier With ±200V Common-Mode Voltage Range



## 7 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 7.1 Device Support

#### 7.1.1 Device Nomenclature

#### Table 7-1. Device Nomenclature

Part Number	Definition
INA148UA INA148UA/2K5	The die is manufactured in CSO: SHE or CSO: TID.

#### 7.1.2 Development Support

## 7.1.2.1 PSpice® for TI

PSpice® for TI is a design and simulation environment that helps evaluate performance of analog circuits. Create subsystem designs and prototype solutions before committing to layout and fabrication, reducing development cost and time to market.

### 7.1.2.2 TINA-TI™ (Free Software Download)

TINA™ is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

#### Note

These files require that either the TINA software (from DesignSoft<sup>™</sup>) or TINA-TI software be installed. Download the free TINA-TI software from the TINA-TI folder.

### 7.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 7.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 7.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 7.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

### 8 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	nanges from Revision " (October 2000) to Revision A (December 2025)	Page
•	Updated Applications links	1
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Added Pin Configuration and Functions section	
•	Added chip site origin (CSO) note to Specification section for clarity	
•	Removed separate Electrical Characteristics Table for Single Supply +5V Supply Range. Added relevan	
	single supply parameters to the combined table	4
•	Added additional test conditions on header and throughout table in Electrical Characteristics and Typical	I
	Characteristics for clarity	<mark>4</mark>
•	Changed from Offset Voltage vs Power Supply to Power-supply rejection ratio for more clarity	4
•	Added additional fabrication process specification for Power-Supply Rejection Ratio in <i>Electrical</i>	
	Characteristics table	4
•	Added test condition " $T_A = -40$ °C to +85°C" for "Gain error vs temperature" in <i>Electrical Characteristics</i>	and
	renamed to "Gain error drift" for clarity	4
•	Added test condition "Continuous to VS / 2" to short-circuit current specification in Electrical Characterist	tics
	for clarity	4
•	Added additional fabrication process specification for Short Circuit current in Electrical Characteristics ta	ıble <mark>4</mark>
•	Added additional fabrication process specification for Bandwidth in <i>Electrical Characteristics</i> table	4
•	Added additional fabrication process specification for 0.1% and 0.01% Settling Time in <i>Electrical</i>	
	Characteristics table	4
•	Changed overload recovery dual supply CSO:SHE specification from 21µs to 4µs to accurately reflect the	ıe
	specification in the Electrical Characteristics table	4
•	Added additional fabrication process specification for Overload Recovery in Electrical Characteristics takes	ole4
•	Changed overload recovery for single supply from 13µs to 3µs to accurately reflect the specification in	
	Electrical Characteristics table	4
•	Moved power supply, operating and specification temperature range specifications from <i>Electrical</i>	
	Characteristics to Recommended Operating Conditions table	4
•	Added all chip site origin (CSO) to typical test conditions in <i>Typical Characteristics</i> section	
•	Added chip site origin (CSO) note to Gain vs Frequency, Common-Mode Rejection vs Frequency, Power	
	Supply Rejection vs Frequency, Short-Circuit Current vs Temperature, Output Voltage Swing vs $R_L$ , Large	
	Signal Capacitive Load Response, and Overload Recovery Time in <i>Typical Characteristics</i> section	
•	Added additional fabrication process curve for Gain vs Frequency, Common-Mode Rejection vs Frequency	
	Power-Supply Rejection vs Frequency, Short-Circuit Current vs Temperature, Output Voltage Swing vs F	
	Large-Signal Capacitive Load Response, and Overload Recovery Time in Typical Characteristics section	
•	Updated Application Information verbiage for more clarity	
•	Added device nomenclature for chip site origin in Device Support	18

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# 9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
INA148UA	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	INA 148UA
INA148UA.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	INA 148UA
INA148UA.B	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	INA 148UA
INA148UA/2K5	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	INA 148UA
INA148UA/2K5.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	INA 148UA
INA148UA/2K5.B	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	INA 148UA

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE OPTION ADDENDUM**

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#### OTHER QUALIFIED VERSIONS OF INA148:

Automotive : INA148-Q1

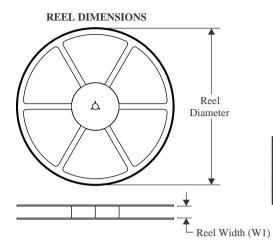
NOTE: Qualified Version Definitions:

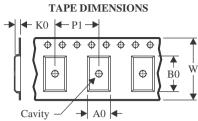
Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 24-Jul-2025

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

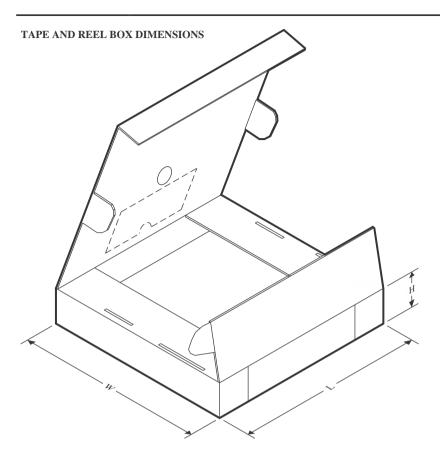


#### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA148UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

**PACKAGE MATERIALS INFORMATION** 

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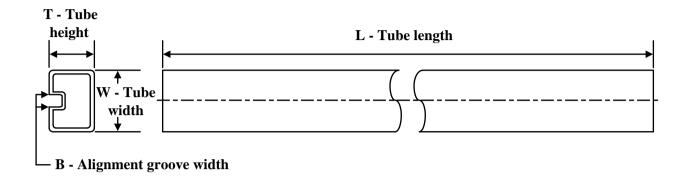
### \*All dimensions are nominal

Ì	Device Package Typ		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	INA148UA/2K5	SOIC	D	8	2500	353.0	353.0	32.0	

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
INA148UA	D	SOIC	8	75	506.6	8	3940	4.32
INA148UA.A	D	SOIC	8	75	506.6	8	3940	4.32
INA148UA.B	D	SOIC	8	75	506.6	8	3940	4.32

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